

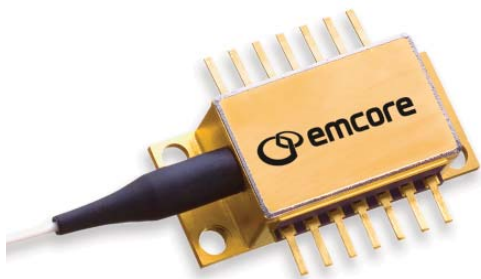
1792 ECCW

Narrow Linewidth CW External Cavity Laser Diode



Analog Lasers & Photodiodes

BROADBAND



Features

- Narrow linewidth, < 10 kHz available
- ITU wavelengths across the C-band
- 100 GHz channel spacing
- 10 mW minimum output power
- Industry standard, high reliability, hermetic 14-pin butterfly package
- Excellent long-term wavelength stability eliminates the need for a wavelength locker
- Back-facet monitor
- Designed to meet Telcordia GR-468 qualification standard
- RoHS Compliant

Applications

- Seismic sensor applications
- Interferometry
- Spectroscopy
- Lidar
- Optical test and instrumentation
- Microwave photonics

The 1792 ECCW series external cavity laser is a cost effective solution for a coherent laser source. The laser is fabricated in a 14-pin hermetically sealed butterfly package that incorporates a bias tee circuit, an integrated thermoelectric cooler (TEC), a thermistor, and a back facet monitor photodiode. The 1792 ECCW provides substantially lower phase noise and a longer coherence length than other semiconductor lasers, including DFB lasers. The wavelength stability is assured by design, eliminating the need for wavelength lockers and complex feedback control circuits.



Performance Highlights

Pigtail Type	Optical Power		Linewidth KHz
	Minimum (mW)	Typical (mW)	
SMF	15	20	50
PMF	10	12	50
	15	20	50

See following pages for complete specifications and conditions.

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Condition	Min	Max	Units
Storage Temperature	T_{STG}	Non-operating	-40	85	°C
Operating Case Temperature	T_{OP}	continuous	-20	75	°C
Forward Current	I_{OP}	CW	-	300	mA
Reverse Voltage	V_R	continuous	-	2	V
Photodiode Forward Current	$I_{MPD,F}$	continuous	-	2	mA
Photodiode Reverse Voltage	$V_{MPD,R}$	continuous	-	10	V
TEC Current ²	I_{TEC}	-	-	1.8	A
TEC Voltage	V_{TEC}	continuous	-	3.5	V
Fiber Bend Radius	R	continuous	35	-	mm
Tensile Strength, Fiber to Case	F	continuous	-	5	N
Lead Soldering Time ³	t_{SOLD}	<260 °C	-	10	sec
Package Mounting Screw Torque ⁴		-	-	0.12	m*N
Operating Humidity: Non-Condensing	X_{OP}	continuous	5	95	%
Storage Humidity: Non-Condensing	X_{OP}	continuous	5	95	%

1792 ECCW

Narrow Linewidth CW External Cavity Laser Diode



Analog Lasers & Photodiodes

BROADBAND

Electrical / Optical Characteristics

Parameter	Symbol	Condition	Min	Type	Max	Units
Minimum Optical Output Power	P_O	15mW Option 10mW Option	15 10	20 12	- -	mW
Optical Linewidth ^{1,2,3,4}	-	Available for all other models	-	25	50	KHz
Threshold Current	I_{TH}	-	-	-	30	mA
Laser Bias Current	T_{OP}	-	-	-	250	mA
Forward Voltage	V_F	CW, $P_O = 10$ mW	-	-	2.0	V
MPD Current	I_{MON}	CW, $P_O = 10$ mW	0.05	-	0.5	mA
MPD Tracking Error	TE	$-10^{\circ}\text{C} < T_C < 65^{\circ}\text{C}$	-	-	± 0.5	dB
TEC Set Temperature ⁵	T_S	Specified for every laser	16	-	35	$^{\circ}\text{C}$
Center Wavelength (100 GHz ITU Grid)	λ_C	See ITU Grid Channel Numbering Table				nm
Wavelength Drift with Case (-10 to 65 $^{\circ}\text{C}$) Temperature	$\Delta \lambda_{T_C}$	Relative to 25 $^{\circ}\text{C}$ Case Temperature	-	-	± 40	pm
Wavelength Offset from DWDM ITU Grid	$\Delta \lambda_{\text{OFFSET}}$	TEC Temperature at T_S	-	-	± 80	pm
Frequency Temperature Coefficient	$\Delta f / \Delta T$	-	-	3.5	5	GHz/ $^{\circ}\text{C}$
Frequency Current Coefficient	$\Delta f / \Delta I$	-	-	200	250	MHz/mA
Optical Isolation	-	$-10^{\circ}\text{C} < T_C < 65^{\circ}\text{C}$	35	-	-	dB
Relative Intensity Noise	RIN	CW, at 200 MHz	-	-155	-	dB/Hz
Side Mode Suppression Ratio	SMSR	CW, $P_O > 1$ mW	40	-	-	dB
Optical Return Loss	ORL	-	40	-	-	dB
TEC Current	I_{TEC}	$T_C = 65^{\circ}\text{C}$, $T_{OP} = T_S$	-	-	+1.5	A
TEC Voltage	V_{TEC}	$T_C = 65^{\circ}\text{C}$, $T_{OP} = T_S$	-	-	+3.0	V
TEC Capacity	ΔT	$T_C = 65^{\circ}\text{C}$	50	-	-	$^{\circ}\text{C}$
Thermistor Resistance	R_{TH}	$T_{OP} = T_S$	9.5	10.0	10.5	K Ω
Thermistor Beta Constant	B	-	-	3891	-	K

ITU Grid Channel Numbering

Channel	Wavelength (nm)	Channel	Wavelength (nm)
60	1529.55	39	1546.12
59	1530.33	38	1546.92
58	1531.12	37	1547.72
57	1531.90	36	1548.51
56	1532.68	35	1549.32
55	1533.47	34	1550.12
54	1534.25	33	1550.92
53	1535.04	32	1551.72
52	1535.82	31	1552.52
51	1536.61	30	1553.33
50	1537.40	29	1554.13
49	1538.19	28	1554.94
48	1538.98	27	1555.75
47	1539.77	26	1556.56
46	1540.56	25	1557.36
45	1541.35	24	1558.17
44	1542.14	23	1558.98
43	1542.94	22	1559.79
42	1543.73	21	1560.61
41	1544.53	20	1561.42
40	1545.32		

1. CW, at rated power., 2. Lorentzian linewidth measured at -30 dB., 3. Gaussian linewidth measured at -20 dB., 4. Linewidth measured with self-delayed heterodyne method at T_S , I_{OP} , 5. TEC temperature at the recommended value.

Ordering Information

Example: 1792-SMF-043-10-50-FA: ECCW, SMF fiber pigtail, ITU channel 43, 1542.94 nm, 10 mW minimum output power, 50kHz linewidth, FC/APC optical connector

